

## Vishay General Semiconductor

## **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.54 \text{ V}$  at  $I_F = 5 \text{ A}$ 



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
V <sub>RRM</sub>	200 V			
I <sub>FSM</sub>	300 A			
E <sub>AS</sub> at L = 60 mH	150 mJ			
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.77 V			
T <sub>J</sub> max.	150 °C			
Package TO-3PW				
Diode variations	Dual common cathode			

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

ROHS COMPLIANT HALOGEN

Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	V60200PGW	UNIT		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	200	V		
Maximum average forward rectified curret (fig. 1)		60	А		
per did	ode I <sub>F(AV)</sub>	30			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	300	А		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH per dio	de E <sub>AS</sub>	150	mJ		
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode	I <sub>RRM</sub>	0.5	А		
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	V/µs		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	$V_{BR}$	200 (minimum)	-	V
Instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.69	-	
	I <sub>F</sub> = 15 A			0.90	-	
	I <sub>F</sub> = 30 A			1.28	1.48	
	I <sub>F</sub> = 10 A	T <sub>A</sub> = 125 °C		0.54	-	
	I <sub>F</sub> = 15 A			0.66	-	
	I <sub>F</sub> = 30 A			0.77	0.85	
Reverse current per diode	V <sub>R</sub> = 180 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	3.4	-	μΑ
		T <sub>A</sub> = 125 °C		4.6	-	mA
	V <sub>R</sub> = 200 V	T <sub>A</sub> = 25 °C		-	210	μΑ
		T <sub>A</sub> = 125 °C		7.5	27	mA

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60200PGW	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	1.5	°C/W	
	per device		0.8	- C/VV	

ORDERING INFORMATION (Example)							
PACKAGE	ACKAGE PREFERRED P/N UNIT WEIGHT (g)			BASE QUANTITY	DELIVERY MODE		
TO-3PW	V60200PGW-M3/4W	4.5	4W	30/tube	Tube		

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

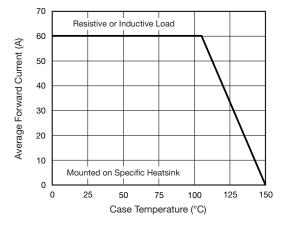


Fig. 1 - Forward Current Derating Curve

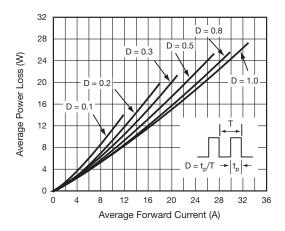


Fig. 2 - Forward Power Loss Characteristics Per Diode



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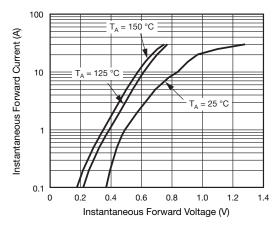


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

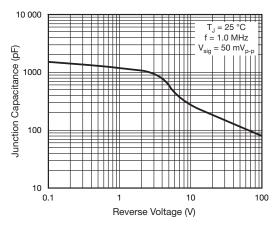


Fig. 5 - Typical Junction Capacitance Per Diode

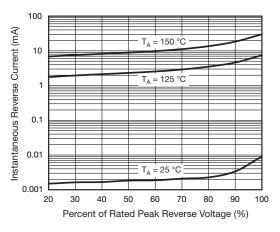


Fig. 4 - Typical Reverse Characteristics Per Diode

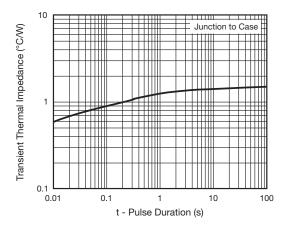
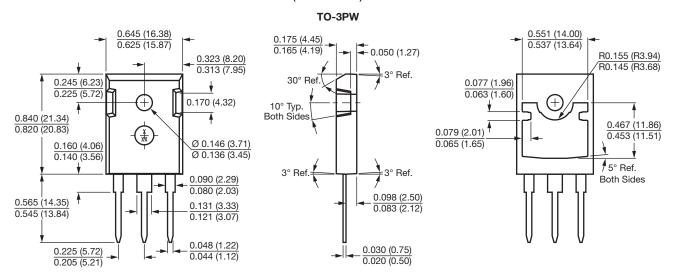


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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